

1.5 Watt P1dB, 3.2 GHz to 4 GHz, Medium Power GaAs Amplifier with Heatsink, 35 dB Gain, 42 dBm IP3 and SMA

The PE15A4076 is a 1.5 Watt coaxial packaged power amplifier operating across a frequency range from 3.2 GHz to 4 GHz. Impressive typical performance includes 35 dB small signal gain, 6 dB noise figure, +32 dBm P1dB, channel output power (OFDM, QAM-64, 54 Mb/s, EVM < 2.5%), and an output 3rd order intercept point of +42 dBm. Design efficiency is 28% (@Pout = +32 dBm), and the maximum RF input power is +7 dBm. This exceptional technical performance is achieved through the use of a hybrid MIC design and advanced GaAs devices. The amplifier supports an integrated heatsink for optimum thermal dissipation and has a bias voltage is +5V typical with a supply current of 1300 mA (@Pout = +32 dBm). The operational temperature range is -40°C to +85°C. The rugged package assembly supports SMA female connectors and RFI and Ground pins. And for highly reliable operation, the model is guaranteed to meet environmental test conditions for Humidity, Shock, Vibration, and Altitude.

Electrical Specifications

(TA = +25°C, DC Voltage = +5Volts, DC Current = 1.3A)

Description	Min	Typ	Max	Unit
Frequency Range	3.2		4	GHz
Small Signal Gain		35		dB
Input Power (CW)			+7	dBm
Channel Power Output*		+25		dBm
Efficiency (PAE) @Pout=+32 dBm		28		%
Output Power (1dB Compression Point)**		+32		dBm
Output 3rd Order Intercept Point		+42		dBm
Reverse Isolation		-50		dB
Noise Figure		6		dB
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input VSWR	1.3:1			
Output VSWR		1.3:1		
Operating DC Voltage	+5	+6		Volts
Operating DC Current @Pout=+32 dBm	1.3			A
Quiescent Current (No Input)	730			mA

**Input Power = -2 dBm
*Modulation: OFDM, QAM-64, 54 Mb/s, EVM<2.5%

Absolute Maximum Rating

Parameter	Absolute Maximum
RF Input Power	+7dBm
Supply Voltage	+7V
Operating Temperature	-40 °C to +85 °C
Storage Temperature	-55 °C to +125 °C

Mechanical Specifications

Size	
Length	3.75 in [95.25 mm]



Features:

- 1.5 Watt Power Amplifier
- 3.2 GHz to 4 GHz
- Small Signal Gain 35 dB typ
- 6 dB Noise Figure
- Output P1dB +32 dBm
- Channel Pout +25 dBm
- Output IP3 +42 dBm
- Max RF Input Power +7 dBm
- Integrated Heatsink
- Reverse DC Protection
- DC Voltage +5Vdc
- DC Current 1300 mA
- Operational Temperature Range -40°C to +85°C
- SMA Female Connectors
- 50 Ohm Design
- Rugged Design meets MIL-STD-202 Test Conditions

Applications:

- Aerospace & Defense
- Test & Measurement
- Microwave Radio Systems
- Military & Commercial Communication Systems
- Research & Development
- SATCOM
- Wireless Communications

Width	2 in [50.8 mm]
Height	1.813 in [46.05 mm]
Weight	0.545 lbs [247.21 g]
Input Connector	SMA Female
Output Connector	SMA Female

Environmental Specifications

Temperature

Operating Range	-40 to +85 deg C
Storage Range	-55 to +105 deg C

Humidity

MIL-STD-202, Method 103B, Condition B

Shock

MIL-STD-202F, Method 213B, Condition B

Vibration

MIL-STD-202F, Method 204D, Condition B

Altitude

MIL-STD-202F, Method 105C, Condition B

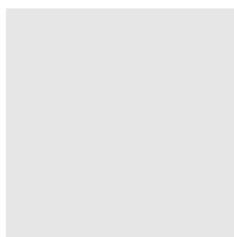
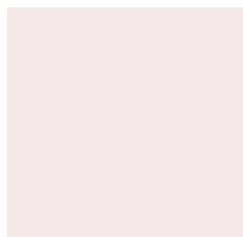
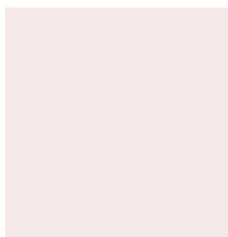
Compliance Certifications

(see [product page](#) for current document)

Plotted and Other Data

Notes:

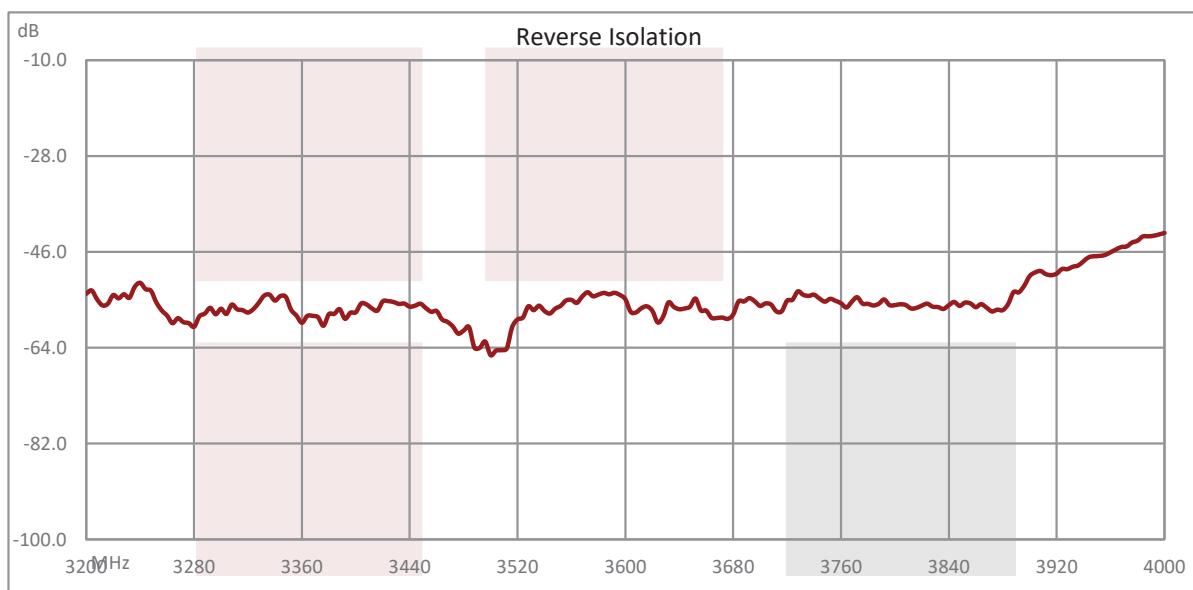
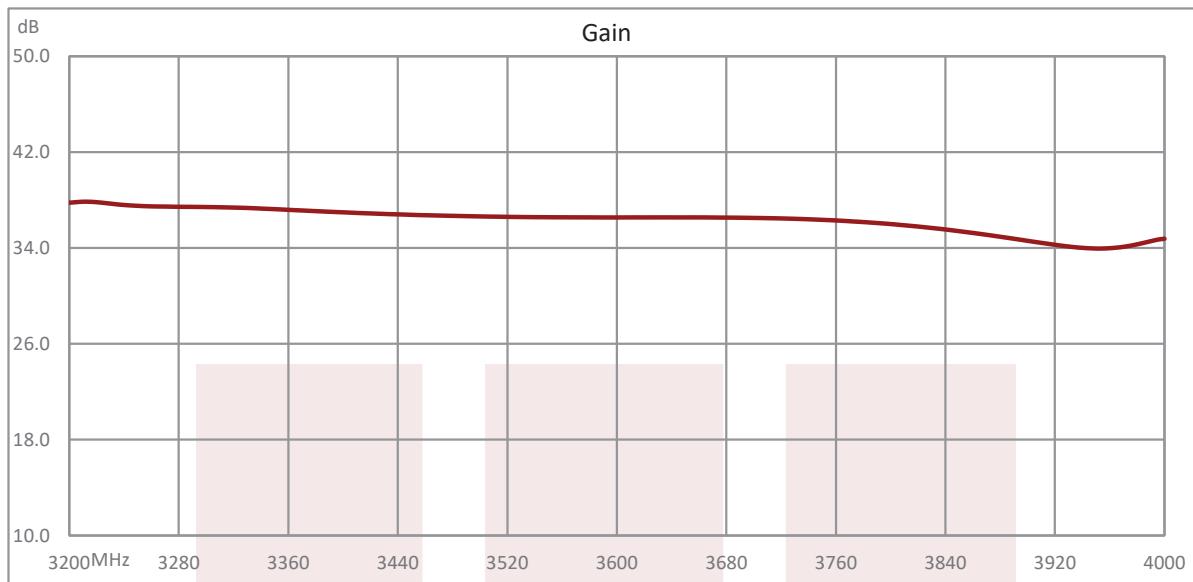
- Values at 25 °C, sea level

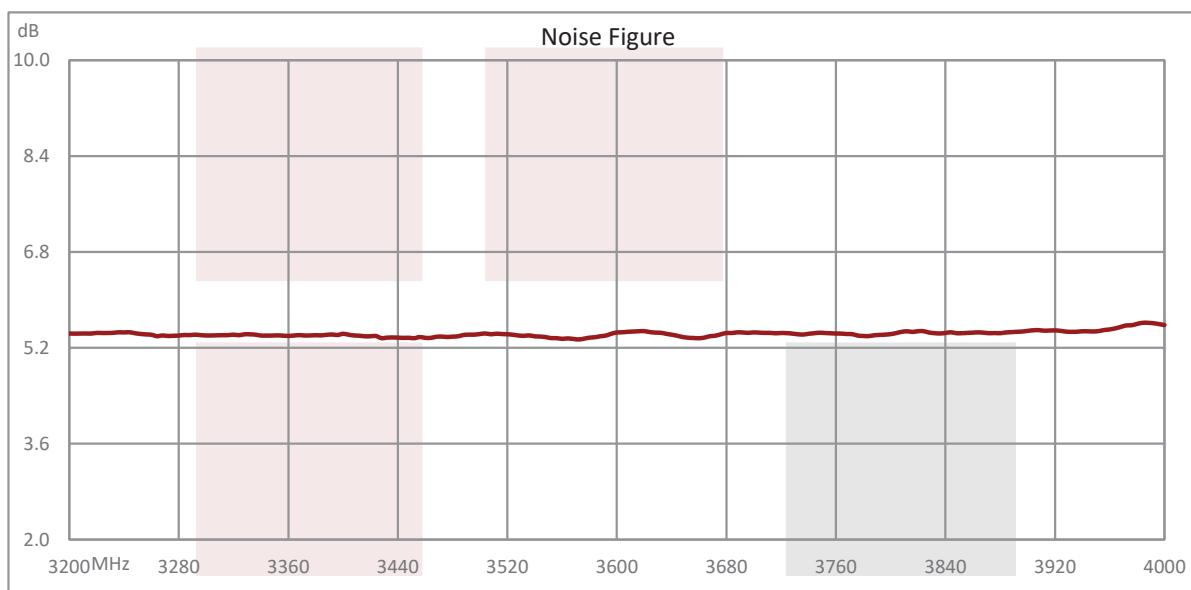
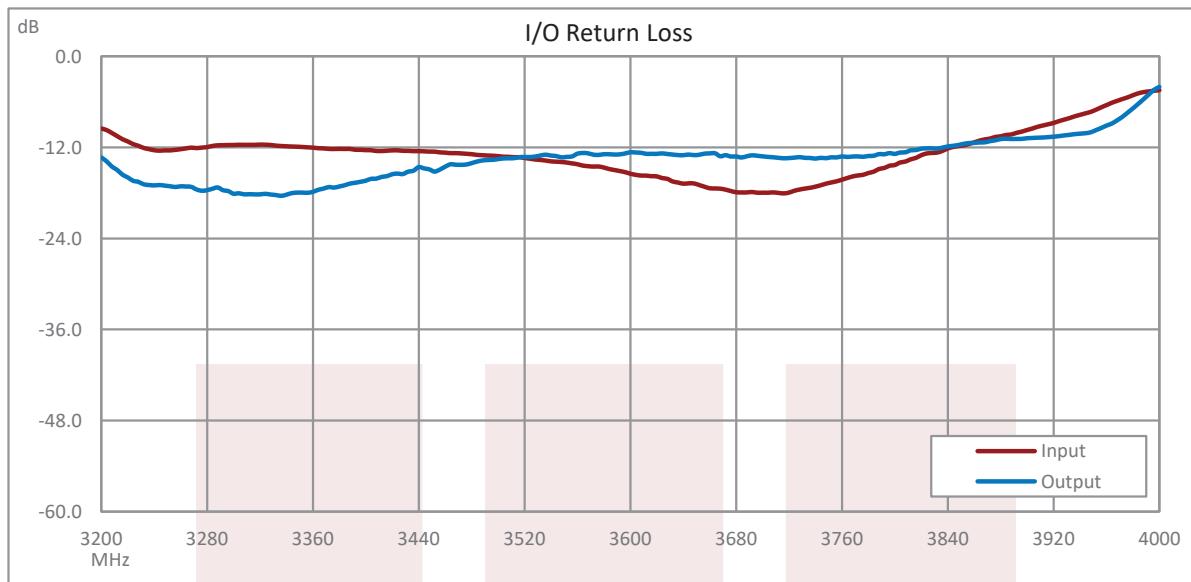


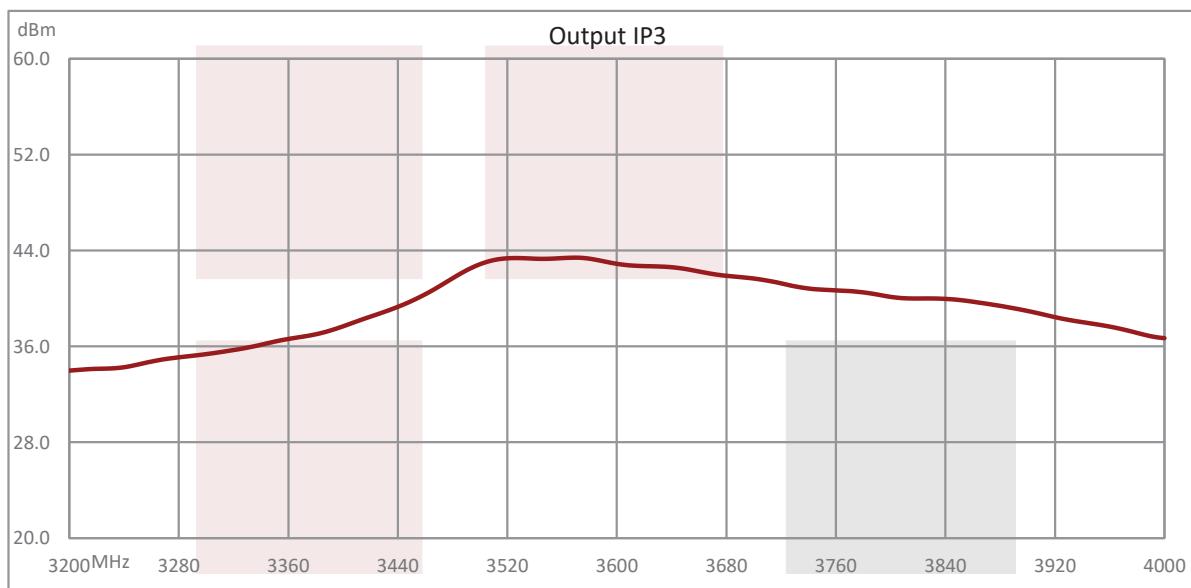
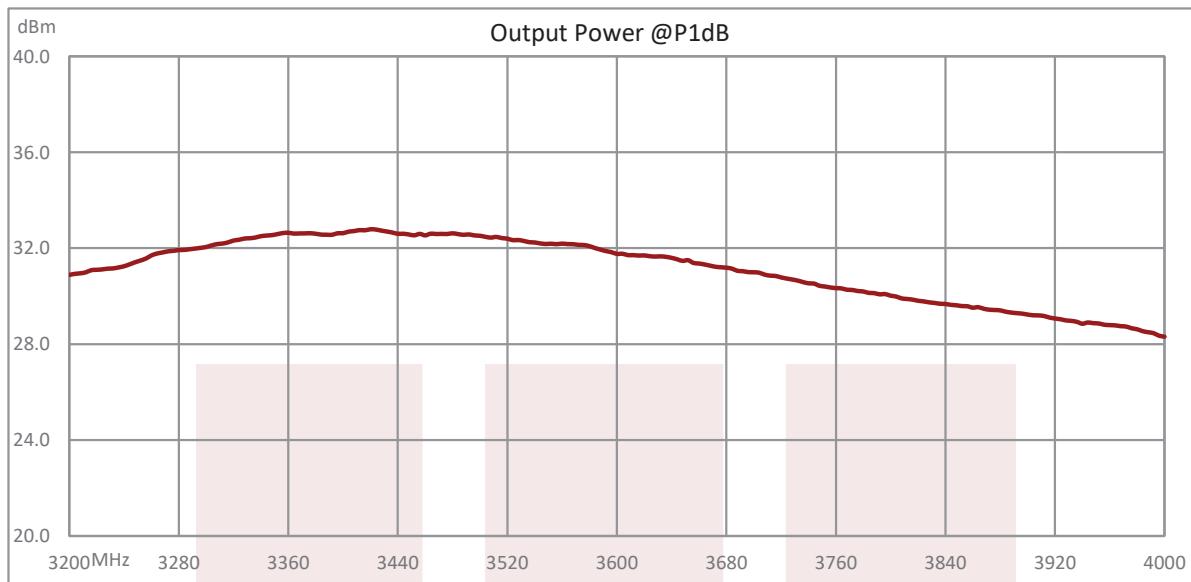
Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
 P_{in} for Small Signal Gain = $P_{1dB-SSG}-10$ dB
 P_{in} for P_{1dB} = $P_{1dB-SSG}+1$ dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 500hm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** - It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

Typical Performance Data







1.5 Watt P1dB, 3.2 GHz to 4 GHz, Medium Power GaAs Amplifier with Heatsink, 35 dB Gain, 42 dBm IP3 and SMA from Fairview Microwave is in-stock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Lewisville, Texas. Fairview Microwave is RF on-demand.

For additional information on this product, please click the following link: [1.5 Watt P1dB, 3.2 GHz to 4 GHz, Medium Power GaAs Amplifier with Heatsink, 35 dB Gain, 42 dBm IP3 and SMA FMAM4076](#)

URL:

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